

/ Descriptions

SOT-89 PNP Silicon PNP transistor in a SOT-89 Plastic Package.

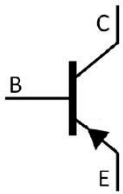
/ Features

High voltage, low saturation voltage, low collector output capacitance, complementary pair with MMBTA42T.

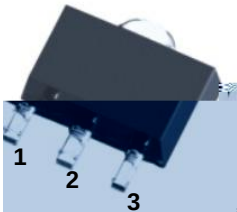
/ Applications

High voltage control circuit.

/ Equivalent Circuit



/ Pinning



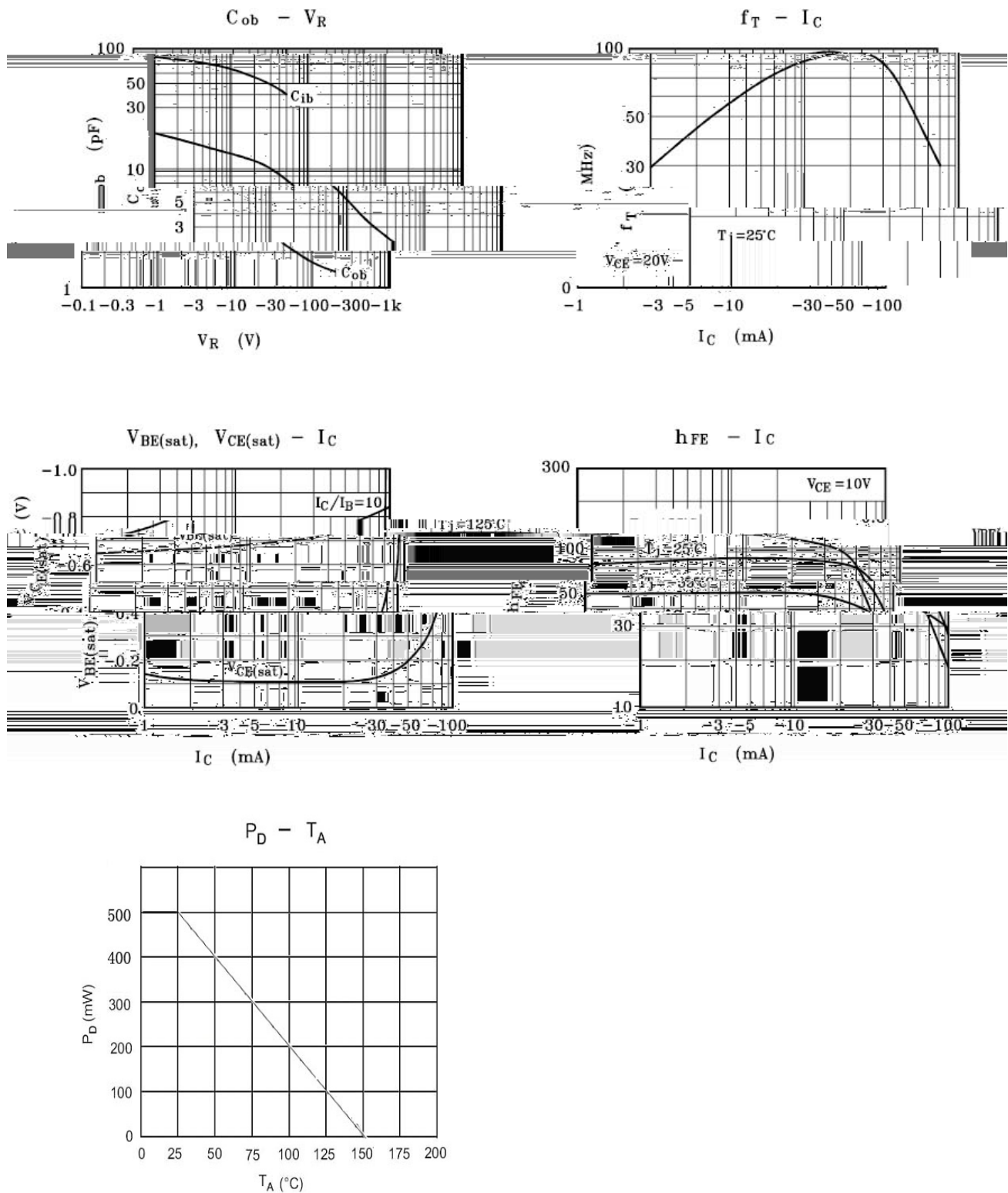
PIN1 Base PIN 2 Collector PIN 3 Emitter

/ Marking

Marking	H2D
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Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-300	V
Collector to Emitter Voltage	V_{CEO}	-300	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-500	mA
Collector Power Dissipation	P_C	500	mW

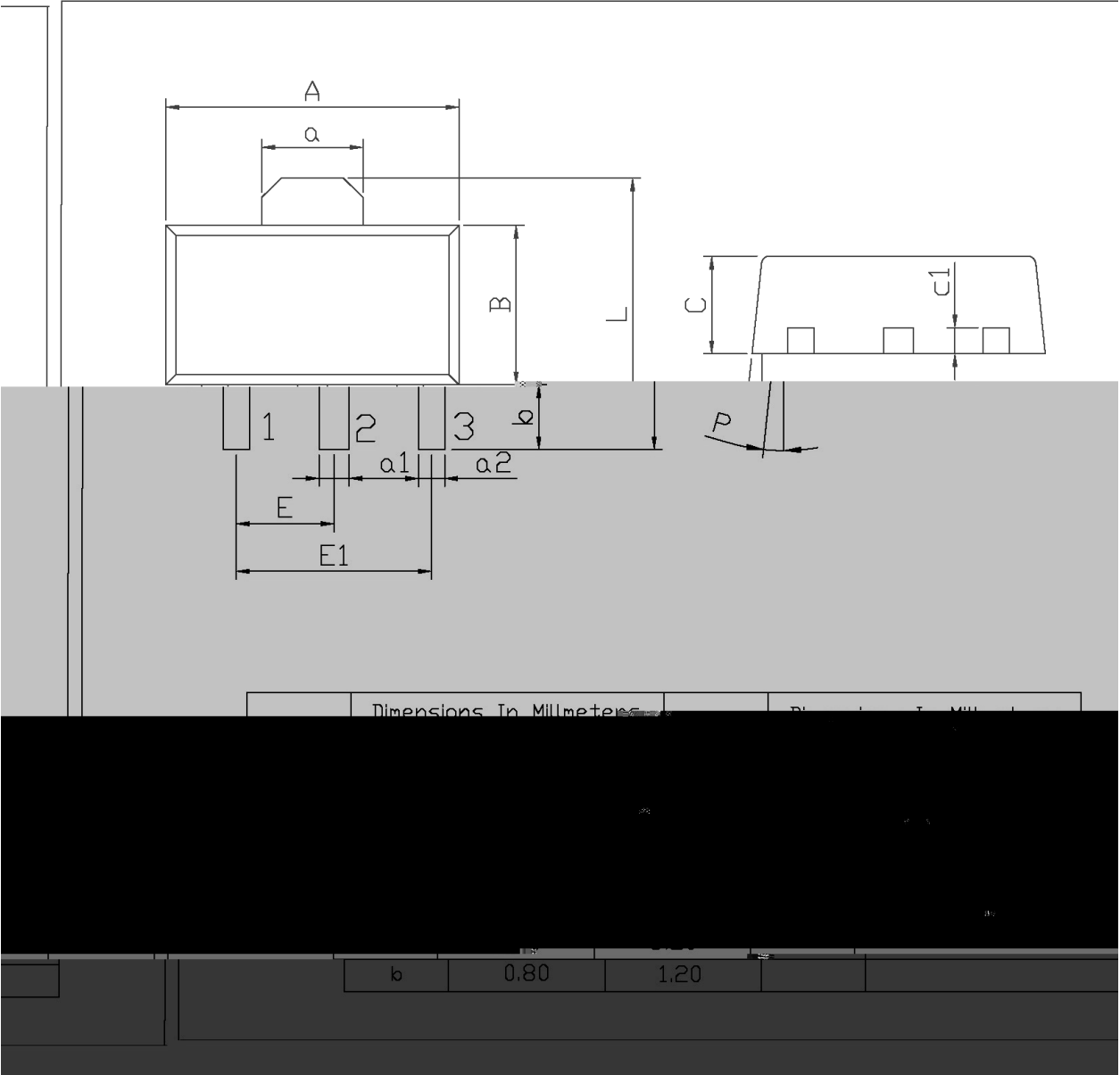
/ Electrical Characteristic Curve



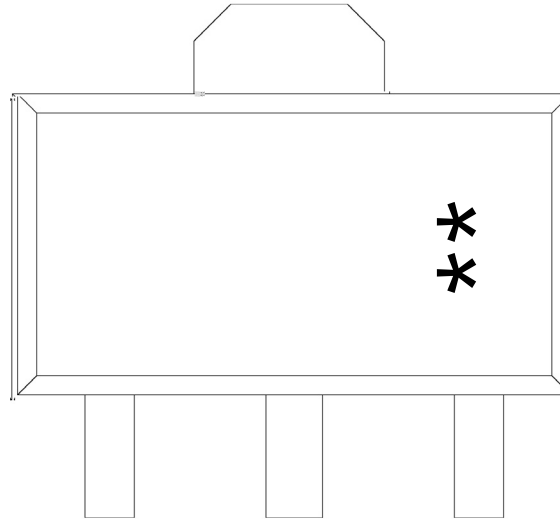
/ Package Dimensions

MMBTA92T

单位: mm



/ Marking Instructions



H

2D

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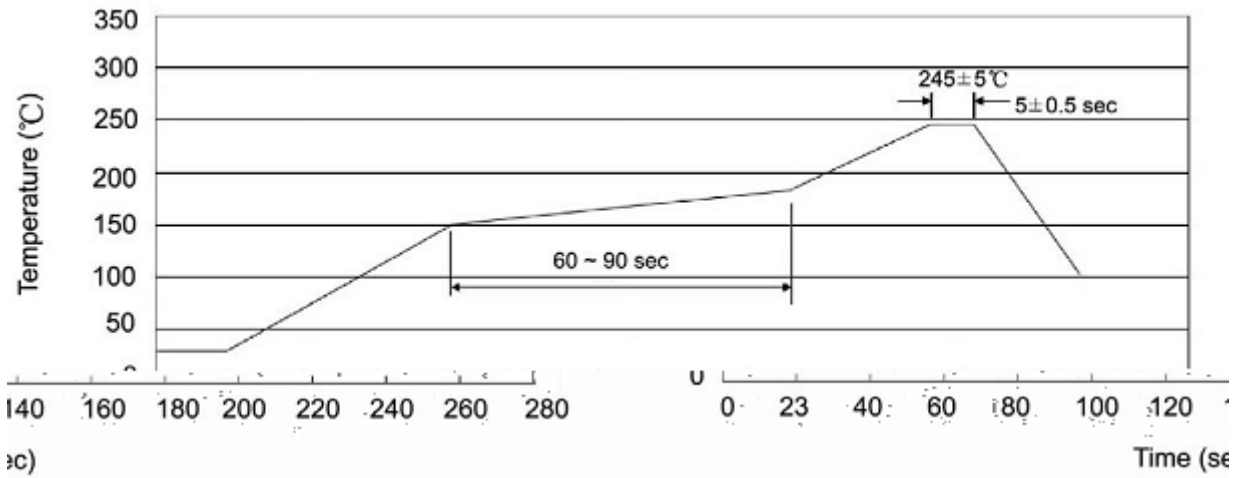
Note:

H: Company Code.

2D: Product Type.

**: Lot No. Code, code change with Lot No.

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Note:

- | | | | | | |
|---|-------|-----|-----------|--------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245±5 | | 5±0.5sec; | | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

/ Packaging SPEC.